

	Type	Hits	Search Text
1	BRS	42	(dummy near1 (metal\$4 or conduct\$4)) near5 ground\$3
2	BRS	130	semiconductor and (occlud\$3 near2 hydrogen)
3	BRS	36	S2 and (FET or MOSFET or transistor)
4	BRS	28	(dummy near1 (metal\$4 or conduct\$4)) near5 float\$3
5	IS&R	5	((("20020185664") or ("6841819") or ("6717267") or ("20010033172") or ("6413847"))).PN.
6	BRS	13916	current adj mirror adj circuit
7	BRS	12525	S6 and (transistor or FET or MOSFET)
8	BRS	6165	S7 and gate
9	BRS	76188	sei ji.in.
10	BRS	1634	("257"/\$.ccls. or "438"/\$.ccls.) and sei ji.in.
11	BRS	375	S10 and transistor
12	BRS	74	S11 and (Ti or titanium)
13	BRS	7053	257/288,300,340,368,383,401,773,770.cc ls.
14	BRS	269	S8 and "257"/\$.ccls.

	DBs
1	US-PGPUB; USPAT; EPO; JPO; DERWENT
2	US-PGPUB; USPAT; EPO; JPO; DERWENT
3	US-PGPUB; USPAT; EPO; JPO; DERWENT
4	US-PGPUB; USPAT; EPO; JPO; DERWENT
5	US-PGPUB; USPAT
6	US-PGPUB; USPAT; EPO; JPO; DERWENT
7	US-PGPUB; USPAT; EPO; JPO; DERWENT
8	US-PGPUB; USPAT; EPO; JPO; DERWENT
9	US-PGPUB; USPAT; EPO; JPO; DERWENT
10	US-PGPUB; USPAT; EPO; JPO; DERWENT
11	US-PGPUB; USPAT; EPO; JPO; DERWENT
12	US-PGPUB; USPAT; EPO; JPO; DERWENT
13	US-PGPUB; USPAT; EPO; JPO; DERWENT
14	US-PGPUB; USPAT; EPO; JPO; DERWENT